

# isc N-Channel MOSFET Transistor

## **R8002ANJ**

### FEATURES

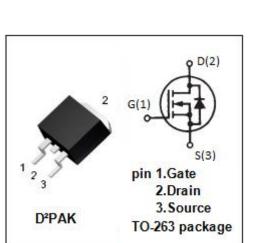
- Drain Current –I\_D= 24A@ T\_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V<sub>DSS</sub>=800V(Min)
- Static Drain-Source On-Resistance
- :  $R_{DS(on)}$  = 4.3  $\Omega$  (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

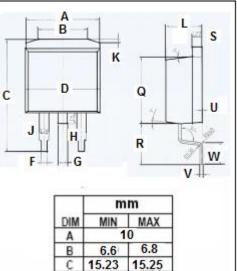
### DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25 C)					
SYMBOL	PARAMETER	VALUE	UNIT		
V <sub>DSS</sub>	Drain-Source Voltage	800	V		
$V_{GS}$	Gate-Source Voltage-Continuous	±30	V		
ID	Drain Current-Continuous	2	А		
I <sub>DM</sub>	Drain Current-Single Pluse	8	А		
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	62	W		
TJ	Max. Operating Junction Temperature	150	°C		
T <sub>stg</sub>	Storage Temperature	-55~150	°C		

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)





Α	1	0	
В	6.6	6.8	
С	15.23	15.25	1
D	10.15	10.17	
F	0.76	0.78	1
G	1.26	1.28	
Н	1.4	1.6	
J	1.33	1.35	1
Κ	0.4	0.6	
L	4.6	4.8	
0	8.69	8.71	
R	5.28	5.30	
S	1.26	1.28	
U	0.0	0.2	1
V	0.37	0.39	
W	2.80	2.82	1

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2.01	°C/W

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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V(BR)DSS	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1mA	800		V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =1mA	3	5	V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 1.0A		4.3	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 800V; V <sub>GS</sub> = 0		100	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 2A; V <sub>GS</sub> = 0		1.5	V

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